LOW VOLTAGE 1:18 CLOCK DISTRIBUTION CHIP

MPC940L

DATASHEET OBSOLETE

The MPC940L is a 1:18 low voltage clock distribution chip with 2.5 V or 3.3 V LVCMOS output capabilities. The device features the capability to select either a differential LVPECL or an LVCMOS compatible input. The 18 outputs are 2.5 V or 3.3 V LVCMOS compatible and feature the drive strength to drive 50 Ω series or parallel terminated transmission lines. With output-to-output skews of 150 ps, the MPC940L is ideal as a clock distribution chip for the most demanding of synchronous systems. The 2.5 V outputs also make the device ideal for supplying clocks for a high performance microprocessor based design. For a similar device at a lower price/performance point, the reader is referred to the MPC9109.

LVPECL or LVCMOS Clock Input

DT

- 2.5 V LVCMOS Outputs for Pentium II Microprocessor Support
- 150 ps Maximum Output-to-Output Skew
- Maximum Output Frequency of 250 MHz
- 32-Lead LQFP Packaging, Pb-Free
- Dual or Single Supply Device:
 - Dual V_{CC} Supply Voltage, 3.3 V Core and 2.5 V Output
 - Single 3.3 V V_{CC} Supply Voltage for 3.3 V Outputs
 - Single 2.5 V V_{CC} Supply Voltage for 2.5 V I/O
- For drop in replacement use 83940DYLF

MPC940L LOW VOLTAGE 1:18 CLOCK DISTRIBUTION CHIP AC SUFFIX 32-LEAD LQFP PACKAGE Pb-FREE PACKAGE CASE 873A-04

With a low output impedance ($\approx 20 \Omega$), in both the HIGH and LOW logic states, the output buffers of the MPC940L are ideal for driving series terminated transmission lines. With a 20 Ω output impedance the 940L has the capability of driving two series terminated lines from each output. This gives the device an effective fanout of 1:36. If a lower output impedance is desired please see the MPC942 data sheet.

The differential LVPECL inputs of the MPC940L allow the device to interface directly with a LVPECL fanout buffer like the MC100EP111 to build very wide clock fanout trees or to couple to a high frequency clock source. The LVCMOS input provides a more standard interface for applications requiring only a single clock distribution chip at relatively low frequencies. In addition, the two clock sources can be used to provide for a test clock interface as well as the primary system clock. A logic HIGH on the LVCMOS_CLK_SEL pin will select the LVCMOS level clock input. All inputs of the MPC940L have internal pullup/pulldown resistors so they can be left open if unused.

The MPC940L is a single or dual supply device. The device power supply offers a high degree of flexibility. The device can operate with a 3.3 V core and 3.3 V output, a 3.3 V core and 2.5 V outputs as well as a 2.5 V core and 2.5 V outputs. The 32-lead LQFP package was chosen to optimize performance, board space and cost of the device. The 32-lead LQFP has a 7x7 mm body size with a conservative 0.8 mm pin spacing.

Pentium II is a trademark of Intel Corporation.



LOGIC DIAGRAM

FUNCTION TABLE

LVCMOS_CLK_SEL	Input
0	PECL_CLK
1	LVCMOS_CLK

- Q0

- Q1–Q16

Q17

POWER SUPPLY VOLTAGES

Supply Pin	Voltage Level
V _{CCI}	2.5 V or 3.3 V ± 5%
V _{CCO}	2.5 V or 3.3 V ± 5%

Table 1. Pin Configurations

Pin	I/O	Туре	Function
PECL_CLK	Input	LVPECL	Reference Clock Input
PECL_CLK	mput		
LVCMOS_CLK	Input	LVCMOS	Alternative Reference Clock Input
LVCMOS_CLK_SEL	Input	LVCMOS	Selects Clock Source
Q0–Q17	Output	LVCMOS	Clock Outputs
V _{cco}		Supply	Output Positive Power Supply
V _{CCI}		Supply	Core Positive Power Supply
GNDO		Supply	Output Negative Power Supply
GNDI		Supply	Core Negative Power Supply

Table 2. Absolute Maximum Ratings⁽¹⁾

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage	-0.3	3.6	V
VI	Input Voltage	-0.3	V _{DD} + 0.3	V
I _{IN}	Input Current		±20	mA
T _{Stor}	Storage Temperature Range	-40	125	°C

1. Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

Table 3. DC Characteristics (T_A = 0° to 70°C, V_{CCI} = 3.3 V ±5%; V_{CCO} = 3.3 V ±5%)

Symbol	Characteristic		Min	Тур	Max	Unit	Condition
V _{IH}	Input HIGH Voltage	CMOS_CLK	2.4		V _{CCI}	V	
VIL	Input LOW Voltage	CMOS_CLK			0.8	V	
V _{PP}	Peak-to-Peak Input Voltage	PECL_CLK	500		1000	mV	
V_{CMR}	Common Mode Range	PECL_CLK	V _{CCI} – 1.4		V _{CCI} – 0.6	V	
V _{OH}	Output HIGH Voltage		2.4			V	I _{OH} = -20 mA
V _{OL}	Output LOW Voltage				0.5	V	I _{OL} = 20 mA
I _{IN}	Input Current				±200	μΑ	
C _{IN}	Input Capacitance			4.0		pF	
C _{pd}	Power Dissipation Capacitance			10		pF	per output
Z _{OUT}	Output Impedance		18	23	28	Ω	
I _{CC}	Maximum Quiescent Supply Cu	rrent		0.5	1.0	mA	

Table 4. AC Characteristics (T_A = 0° to 70°C, V_{CCI} = 3.3 V ±5%; V_{CCO} = 3.3 V ±5%)

Symbol	Cha	racteristic	Min	Тур	Max	Unit	Condition
F _{max}	Maximum Input Freq	uency			250	MHz	
t _{PLH}	Propagation Delay	$\begin{array}{l} PECL_CLK \leq 150 \; MHz \\ CMOS_CLK \leq 150 \; MHz \end{array}$	2.0 1.8	2.7 2.5	3.4 3.0	ns	
t _{PLH}	Propagation Delay	PECL_CLK > 150 MHz CMOS_CLK > 150 MHz	2.0 1.8	2.9 2.4	3.7 3.2	ns	
t _{sk(o)}	Output-to-Output Ske	ew PECL_CLK CMOS_CLK			150 150	ps	
t _{sk(pp)}	Part-to-Part Skew	$\begin{array}{l} PECL_CLK \leq 150 \; MHz \\ CMOS_CLK \leq 150 \; MHz \end{array}$			1.4 1.2	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew	PECL_CLK > 150 MHz CMOS_CLK > 150 MHz			1.7 1.4	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew	PECL_CLK CMOS_CLK			850 750	ps	Note ⁽²⁾
DC	Output Duty Cycle	f_{CLK} < 134 MHz $f_{CLK} \le 250$ MHz	45 40	50 50	55 60	% %	Input DC = 509 Input DC = 509
t _r , t _f	Output Rise/Fall Time	e	0.3		1.1	ns	0.5 – 2.4 V

1. Across temperature and voltage ranges. Includes output skew.

2. For specific temperature and voltage. Includes output skew.

Symbol	Characteristic	:	Min	Тур	Max	Unit	Condition
V _{IH}	Input HIGH Voltage	CMOS_CLK	2.4		V _{CCI}	V	
V _{IL}	Input LOW Voltage	CMOS_CLK			0.8	V	
V _{PP}	Peak-to-Peak Input Voltage	PECL_CLK	500		1000	mV	
V _{CMR}	Common Mode Range	PECL_CLK	V _{CCI} – 1.4		V _{CCI} – 0.6	V	
V _{OH}	Output HIGH Voltage		1.8			V	I _{OH} = -12 mA
V _{OL}	Output LOW Voltage				0.5	V	I _{OL} = 12 mA
I _{IN}	Input Current				±200	μΑ	
C _{IN}	Input Capacitance			4.0		pF	
C _{pd}	Power Dissipation Capacitance	•		10		pF	per output
Z _{OUT}	Output Impedance			23		Ω	
I _{CC}	Maximum Quiescent Supply Cu	urrent		0.5	1.0	mA	

Table 5. DC Characteristics (T_A = 0° to 70°C, V_{CCI} = 3.3 V ±5%; V_{CCO} = 2.5 V ±5%)

Table 6. AC Characteristics (T_A = 0° to 70°C, V_{CCI} = 3.3 V ±5%; V_{CCO} = 2.5 V ±5%)

Symbol	Characteristic	Min	Тур	Max	Unit	Condition
F _{max}	Maximum Input Frequency			250	MHz	
t _{PLH}	$\begin{array}{llllllllllllllllllllllllllllllllllll$		2.8 2.5	3.5 3.0	ns	
t _{PLH}	Propagation Delay PECL_CLK > 150 M CMOS_CLK > 150 M		2.9 2.5	3.8 3.3	ns	
t _{sk(o)}	Output-to-Output Skew PECL_C CMOS_C			150 150	ps	
t _{sk(pp)}	$\begin{array}{llllllllllllllllllllllllllllllllllll$			1.5 1.3	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew PECL_CLK > 150 M CMOS_CLK > 150 M			1.8 1.5	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew PECL_C CMOS_C			850 750	ps	Note ⁽²⁾
DC	$\begin{array}{llllllllllllllllllllllllllllllllllll$		50 50	55 60	% %	Input DC = 50% Input DC = 50%
t _r , t _f	Output Rise/Fall Time	0.3		1.2	ns	0.5 – 1.8 V

1. Across temperature and voltage ranges. Includes output skew.

2. For specific temperature and voltage. Includes output skew.

Symbol	Characteristic	;	Min	Тур	Мах	Unit	Condition
V _{IH}	Input HIGH Voltage	CMOS_CLK	2.0		V _{CCI}	V	
V _{IL}	Input LOW Voltage	CMOS_CLK			0.8	V	
V _{PP}	Peak-to-Peak Input Voltage	PECL_CLK	500		1000	mV	
V _{CMR}	Common Mode Range	PECL_CLK	V _{CCI} – 1.0		V _{CCI} – 0.6	V	
V _{OH}	Output HIGH Voltage		1.8			V	I _{OH} = -12 mA
V _{OL}	Output LOW Voltage				0.5	V	I _{OL} = 12 mA
I _{IN}	Input Current				±200	μA	
C _{IN}	Input Capacitance			4.0		pF	
C _{pd}	Power Dissipation Capacitance)		10		pF	per output
Z _{OUT}	Output Impedance		18	23	28	Ω	
I _{CC}	Maximum Quiescent Supply Cu	urrent		0.5	1.0	mA	

Table 7. DC Characteristics ($T_A = 0^\circ$ to 70°C, $V_{CCI} = 2.5 \text{ V} \pm 5\%$; $V_{CCO} = 2.5 \text{ V} \pm 5\%$)

Table 8. AC Characteristics (T_A = 0° to 70°C, V_{CCI} = 2.5 V ±5%; V_{CCO} = 2.5 V ±5%)

Symbol	Characteristic	Min	Тур	Max	Unit	Condition
F _{max}	Maximum Input Frequency			200	MHz	
t _{PLH}	$\begin{array}{llllllllllllllllllllllllllllllllllll$		4.0 3.1	5.2 4.0	ns	
t _{PLH}	Propagation Delay PECL_CLK > 150 N CMOS_CLK > 150 N		3.8 3.1	5.0 4.0	ns	
t _{sk(o)}	Output-to-Output Skew PECL_C CMOS_C			200 200	ps	
t _{sk(pp)}	$\begin{array}{llllllllllllllllllllllllllllllllllll$			2.6 1.7	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew PECL_CLK > 150 M CMOS_CLK > 150 M			2.2 1.7	ns	Note ⁽¹⁾
t _{sk(pp)}	Part-to-Part Skew PECL_C CMOS_C			1.2 1.0	ns	Note ⁽²⁾
DC	$\begin{array}{c} \mbox{Output Duty Cycle} & f_{CLK} < 134 \ \mbox{M} \\ f_{CLK} \leq 200 \ \mbox{M} \end{array}$		50 50	55 60	% %	Input DC = 50% Input DC = 50%
t _r , t _f	Output Rise/Fall Time	0.3		1.2	ns	0.5 - 1.8 V

1. Across temperature and voltage ranges. Includes output skew.

2. For specific temperature and voltage. Includes output skew.



Figure 1. LVCMOS_CLK MPC940L AC Test Reference for V_{CC} = 3.3 V and V_{CC} = 2.5 V



Figure 2. PECL_CLK MPC940L AC Test Reference for V_{CC} = 3.3 V and V_{CC} = 2.5 V



Figure 3. Propagation Delay (t_{PD}) Test Reference



The time from the PLL controlled edge to the non controlled edge, divided by the time between PLL controlled edges, expressed as a percentage.

Figure 5. Output Duty Cycle (DC)



Figure 7. Output Transition Time Test Reference



Figure 4. LVCMOS Propagation Delay (t_{PD}) Test Reference



The pin-to-pin skew is defined as the worst case difference in propagation delay between any two similar delay paths within a single device.

Figure 6. Output-to-Output Skew T_{SK(O)}



Figure 8. Input Transition Time Test Reference

PACKAGE DIMENSIONS



© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICA	L OUTLINE	PRINT VERSION NO	JT TO SCALE	
TITLE:	DOCUMENT NE]: 98ASH70029A	RE∨: C		
LOW PROFILE QUAD FLAT PA	· · · · ·	CASE NUMBER: 873A-04 01 APR 200			
32 LEAD, 0.8 PITCH (7 X	STANDARD: JE	DEC MS-026 BBA			

CASE 873A-04 ISSUE C 32-LEAD LQFP PACKAGE





© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICA	L OUTLINE	PRINT VERSION NE	JT TO SCALE
TITLE:	<i>,</i> ,	DOCUMENT NO]: 98ASH70029A	RE∨: C
	LOW PROFILE QUAD FLAT PACK (LQFP) 32 LEAD, 0.8 PITCH (7 X 7 X 1.4)			01 APR 2005
	× / / ۱.+)	STANDARD: JE	DEC MS-026 BBA	

PAGE 2 OF 3

CASE 873A-04 ISSUE C 32-LEAD LQFP PACKAGE

() IDT.

PACKAGE DIMENSIONS

NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.

2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5-1994.

 $\overline{3}$ datums a, b, and d to be determined at datum plane H.

 $\overline{4.}$ dimensions to be determined at seating plane datum c.

5 DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE MAXIMUM DIMENSION BY MORE THAN 0.08 MM. DAMBAR CANNOT BE LOCATED ON THZ LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD OR PROTRUSION: 0.07 MM.

/6. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 MM PER SIDE. DIMENSIONS ARE MAXIMUM PLASTIC BODY SIZE DIMENSIONS INCLUDING MOLD MISMATCH.

 $/\overline{2}$ exact shape of each corner is optional.

8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 MM AND 0.25 MM FROM THE LEAD TIP.

© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.	MECHANICAL OUTLINE		PRINT VERSION NOT TO SCALE	
TITLE:	DOCUMENT NO: 98ASH70029A		RE∨∶C	
LOW PROFILE QUAD FLAT P	CASE NUMBER: 873A-04		01 APR 2005	
32 LEAD, 0.8 PITCH (7 X	7 X 1.4)	STANDARD: JE	DEC MS-026 BBA	

PAGE 3 OF 3

CASE 873A-04 ISSUE C 32-LEAD LQFP PACKAGE



Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Termperature
MPC940LAC	MPC940LAC	Lead-Free, 32 Lead LQFP	Tray	0°C to 70°C
MPC940LACR2	MPC940LAC	Lead-Free, 32 Lead LQFP	2500 Tape & Reel	0°C to 70°C

Revision History Sheet

Rev	Table	Page	Description of Change	Date
8		1	NRND – Not Recommend for New Designs.	12/20/12
8		1	Product Discontinuation Notice - PDN CQ-15-02.	5/6/15
9		1	Obsolete per Product Discontinuation Notice - PDN CQ-15-02.	10/4/16



Corporate Headquarters 6024 Silver Creek Valley Road San Jose, CA 95138 USA www.IDT.com

Sales

1-800-345-7015 or 408-284-8200 Fax: 408-284-2775 www.IDT.com/go/sales

Tech Support www.IDT.com/go/support

DISCLAIMER Integrated Device Technology, Inc. (IDT) reserves the right to modify the products and/or specifications described herein at any time, without notice, at IDT's sole discretion. Performance specifications and operating parameters of the described products are determined in an independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in applications involving extreme environmental conditions or in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are trademarks or registered trademarks of IDT and its subsidiaries in the United States and other countries. Other trademarks used herein are the property of IDT or their respective third party owners. For datasheet type definitions and a glossary of common terms, visit www.idt.com/go/glossary. Integrated Device Technology, Inc.. All rights reserved.